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System for reducing the coherence of laser radiation

The invention relates to a system for reducing the
5 coherence of a wavefront-emitting laser radiation, in
particular for a projection objective in semiconductor
lithography, a first partial beam of the laser beam
impinging on a surface of a resonator body being
partially reflected and a second partial beam of said
10 laser beam entering the resonator body and emerging
from the resonator body again after a plurality of
total reflections at least approximately in the region
of the entrance location and being forwarded with the
first partial beam jointly to an illumination plane.
15 The invention also relates to a projection exposure
apparatus with a laser as a light source, an
illumination system and a projection objective.

In the case of projection objectives in semiconductor
20 lithography, it is necessary to illuminate the mask,
also called reticle, as homogeneously as possible by
means of an illumination system. In this case, however,
there is a problem when using pulsed laser light in
terms of high temporal coherence of the laser
25 radiation, as a result of which the homogeneity is
disrupted by speckle, that is to say differences in
bright/dark. It has already been proposed, therefore,
to use the arrangement of a resonator body in the form
of a prism having three corners to split the laser beam
30 when it impinges on the resonator body, to be precise
into a partially reflected partial beam and a second
partial beam, which enters the resonator body, emerges
from the resonator body again after corresponding total
reflections in the region of the entrance location and
35 is subsequently recombined with the reflected partial
beam. In this way, the laser pulses are practically
"chopped" into a plurality of partial beams which
arrive temporally successively at the illumination

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plane, e.g. the reticle plane in the case of use in semiconductor lithography. The purpose in this case is to make the time interval between two pulses so long that it is longer than the so-called temporal coherence
5 of the laser radiation. This means that the beam bundles are no longer capable of interference, that is to say that they can no longer form any interference. This measure is intended to result in an improvement in the illumination homogeneity.

10

With regard to the prior art, reference is made to EP 1 107 089 A2, US 6,238,063 B1 and the Patent Abstract of Japan 01198759A.

15 The present invention is based on the object of providing a system with which the illumination homogeneity can be improved even further.

According to the invention, this object is achieved by
20 virtue of the fact that the resonator body is formed in such a way that in addition to the splitting into partial beams, the wavefronts and at least one partial beam are modulated during a laser pulse, the partial beams which are reflected at the resonator body and
25 which enter the resonator body being superimposed downstream of the resonator body, and the resonator body being provided with a phase plate having varying local phase distribution.

30 In addition to the known splitting of the laser beam into partial beams which are no longer temporally coherent with respect to one another, a modulation of the wavefronts of the laser radiation is also performed according to the invention. This gives rise to
35 different wavefronts (local phase distributions) during a single laser pulse. To put it another way: as a result of superimposing different speckle patterns during a pulse, it is possible in this way to achieve a

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significant increase in the illumination homogeneity through averaging over a plurality of speckle distributions.

5 By means of the combination according to the invention of temporally offset wavefronts which are additionally modulated as well and thus acquire different phase distributions, it is possible to achieve a very high homogeneity by means of averaged speckle patterns. A
10 phase plate which is fitted in the resonator body is suitable for this purpose.

In one advantageous configuration of the invention, it may be provided that the resonator body is formed as a
15 prism having at least five corners. This is because it has been established that in comparison with a resonator body having three corners, at the generally used wavelengths of the laser beams, in particular in the VUV range (vacuum ultraviolet spectral range) or
20 shorter, excessively steep deflection angles arise in the prism, with the result that total reflections do not occur in each case, but rather partial emergences with corresponding light losses. When using a prism having at least five corners, at least four reflections
25 are generated, and generally minimum angles of 37 degrees can be complied with, so that total reflections always occur. In this case, calcium fluoride, in particular, has been found as a material for the resonator body according to the invention. It
30 goes without saying, however, that other materials such as e.g. magnesium fluoride and quartz are also possible for this purpose.

Further various measures are conceivable for the
35 modulation of a wavefront.

If the phase plate has a varying thickness, in accordance with one development of the invention, then

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correspondingly spatially offset wavefronts arise. In this case, varying thickness changes - relative to a direction transversely with respect to the beam direction - should occur at a distance corresponding to the order of magnitude of the spatial coherence length of the laser radiation, which should be fully modulated.

In one advantageous configuration of the invention, it may be provided that the phase plate is formed as a diffractive optical element (DOE) which is operated at the zeroth order of diffraction. A diffractive optical element is normally used at the first or else a higher order of diffraction. In order to achieve the wavefront modulation, however, the diffractive optical element (DOE) will be used at the zeroth order of diffraction, where the laser light passes through without any refraction.

A further possibility consists in the use of a diffusing screen as a phase plate.

The wavefront modulation according to the invention can also be achieved by forming the resonator body, e.g. the prism having the at least five corners in asymmetrical fashion. This may be effected e.g. by means of an asymmetrical, i.e. non-mirror-symmetrical, embodiment of at least one side of the prism.

A further solution or else a combination with an asymmetrical resonator body consists in choosing the beam guiding of the laser beam such that the centroid beam impinges eccentrically on the resonator body. In this case, modulations of the wavefront are likewise created as the partial beam circulates in the resonator body.

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If the surface on which the laser beam impinges is provided with a splitter layer configured in such a way that the entrance angle can thereby be altered, the application possibilities can also be enhanced since
5 the angle dependence can be at least partially reduced. By means of the splitter layer, it is thus possible to vary the entrance angle and thus also the ratio of the reflected partial beam and the partial beam entering the resonator body.

10

In order, moreover, additionally to achieve wavefront modulations, the splitter layer may e.g. be formed with a varying thickness and/or non-homogeneously. A dielectric layer with a splitting ratio of 33:67 or
15 1/3:2/3 can advantageously be used as the splitter layer.

Exemplary embodiments of the invention are illustrated in principle below with reference to the drawings.

20

In the figures:

figure 1 shows a schematic construction of a projection exposure apparatus with a light
25 source, an illumination system and a projection objective;

figure 2 shows a pentaprism as a resonator body with a phase plate;

30

figure 3a shows a cross section through a phase plate according to figure 2;

figure 3b shows a cross section through a further
35 embodiment of a phase plate;

figure 4 shows a pentaprism with two asymmetrical sides;

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figure 5 shows a pentaprism with a splitter layer on a surface.

5 As can be seen from figure 1, a projection exposure apparatus 1 has a light source 2 formed as a laser, an illumination system 3 for illuminating a field in a plane 4 in which a structure-bearing mask 4a is arranged, and also a projection objective 5 for imaging
10 the structure-bearing mask 4a in the plane 4 onto a light-sensitive substrate 6. The projection objective 5 has a plurality of optical elements 7 in its housing 8. The projection exposure apparatus 1 serves for producing semiconductor components, such as e.g.
15 computer chips.

In the present exemplary embodiment, a resonator body 9, 9' is arranged between the laser 2 and the illumination system 3 for the purpose of reducing the,
20 in particular, temporal coherence of a laser radiation 10 of the laser 2.

Figure 2 shows a pentaprism as resonator body 9.

25 For simplification, only the centroid beam of the incident laser beam bundle 10 is illustrated and, moreover, just the laser beam 10 is referred to below. It goes without saying that a beam bundle is present in practice. A $\lambda/2$ plate 18 is used for setting the
30 degree of polarization (between unpolarized and linearly polarized) of the laser beam 10. The laser beam 10 impinging on a surface 11 of the prism 9 is split into a first partial beam 10a, which is reflected at the surface 11, and a partial beam 10b, which enters
35 the resonator body 9 and emerges there from the resonator body 9 again after a plurality of total reflections at the entrance location and is combined there with the first partial beam 10a. The two partial

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beams are subsequently passed to an illumination plane, in this case the plane 4 with the structure-bearing mask. Four total reflections occur in the pentagonal prism illustrated. In the case of a prism having more
5 corners, correspondingly more total reflections are present.

In accordance with figure 2, a phase plate 12 projects into the prism 9, said phase plate being introduced
10 into the prism 9 in such a way that the circulating partial beam 10b, which impinges approximately perpendicularly on a front surface 13 of the phase plate 12, has to penetrate through the latter. The phase plate 12 causes a varying local phase
15 distribution. For this purpose, the phase plate 12 has a varying thickness, as can be seen from the enlarged cross-sectional illustrations in accordance with figures 3a and 3b. As can be seen, the different thicknesses of the phase plate 12 vary in the
20 transverse direction with respect to the beam direction in their width s . In this case - depending on the laser used and the wavelength thereof - the largest width s is intended to be of the order of magnitude of the spatial coherence length of the laser radiation used.
25 In the case of excimer lasers, the value for s lies between 0.05 and 1 mm, a possible beam expansion correspondingly increasing the value.

The thickness difference between the maximum and
30 minimum thicknesses of the plate should be of the order of magnitude of a few wavelengths of the light used. At the wavelengths mentioned above, this should be between $a = 200$ to 500 nm.

35 The base thickness of the phase plate b may be in the region of 500 μm .

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The distribution of the width differences s and the thickness differences a should be as random as possible in order also to obtain a relatively random phase distribution on the wavefront. In this way, the optical path lengths are locally different and, in the case of the reunited partial beams 10a and 10b downstream of the resonator body 9, correspondingly temporally different partial beams are obtained which, moreover, are additionally modulated with respect to the wavefront. In this way, the individual pulses can be so short in terms of their duration and in terms of phase distribution that an interference capability is no longer provided.

In the embodiment in accordance with figure 3b, the structure of the phase plate 12 is embodied in tapering or prismatic fashion, thereby achieving improved beam expansion.

With the use of a pentagonal prism, angles of reflection which are greater than 37 degrees result, whereby total reflections occur in the interior. The exemplary embodiment illustrated was designed such that all the angles of total reflection are identical and are approximately 55 degrees.

Calcium fluoride can be used as material for the prism. The crystal orientation of the CaF_2 prism 9 is chosen such that the first (100) crystal plane forms an angle of 45° with light entrance plane, entrance face or surface 11 and is perpendicular to the side face 14. The second (100) crystal plane lies parallel to the side face 14 of the prism 9.

In this way, the intrinsic birefringence, which is significant at the wavelength of 157 nm and 193 nm, does not affect the polarization of the circulating beam if the light at the entrance surface 11 is

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linearly polarized and the oscillation direction of the electric field strength vector is parallel (p-polarized) or perpendicular (s-polarized) with respect to the plane of incidence. The light emerges
5 from the prism 9 again in s- or p-polarized fashion.

If the incident beam 10 comprises unpolarized light, then the crystal orientation is not of importance and the prism 9 made of CaF_2 can be oriented arbitrarily.
10

A corresponding possibility consists in producing the block from MgF_2 (transparent at 157 nm and 193 nm, highly birefringent). If there is unpolarized light at the entrance, then the crystal orientation with respect
15 to the prism faces can likewise be chosen arbitrarily.

If the light at the entrance plane or entrance surface 11 is linearly polarized (s- or p-polarized) and if the light is intended to emerge again in linearly polarized
20 fashion, then the crystal orientation must be chosen such that the oscillation direction of the incident electric field strength vector is parallel to the fast (direction with extraordinary refractive index) or slow (direction with ordinary refractive index) crystal
25 axis.

In this case, birefringence does not take place and the polarization state is maintained.

30 The phase plate 12 used may be a diffractive optical element which is optimized to the zeroth order of diffraction, at which impinging light passes through without any diffraction.

35 The phase plate 12 used may also be a diffusing screen.

Figure 4 shows a prism in pentagonal form, an offset being present or the prism body being formed in

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asymmetrical fashion. As can be seen, one side, namely the first side 15, on which the partial beams 10b impinge is shifted downward by the distance d. The mirror symmetry is thus disrupted, which also applies to the subsequent side 16. What is likewise achieved in this way is that the reflected partial beam 10a and the partial beam 10b circulating in the prism 9' and thus ultimately all the partial beams run in a manner temporally and spatially offset with respect to one another. The distance d may be of the order of magnitude of 0.1 mm.

If necessary, it is additionally possible to introduce a phase plate 12 (illustrated by broken lines in figure 4) corresponding to the configuration according to figure 2, whereby the modulation of wavefronts is even more variable.

Figure 5 shows a configuration of a prism 9, likewise in pentagonal form, a splitter layer 17 additionally being applied on the entrance surface 11.

The splitter layer may be e.g. a dielectric layer having a splitting ratio of 1/3:2/3. The splitter layer firstly has the task of influencing the entrance angle of the partial beam 10b into the prism 9. This can be chosen as desired according to the configuration and material of the splitter layer.

If the splitter layer furthermore additionally has a varying thickness, then a modulation of the wavefront is additionally achieved as well in a similar manner to that in the case of the phase plate (illustrated by broken lines in figure 5). The same is possible by means of an inhomogeneous or non-homogeneous embodiment of the splitter layer.

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The exemplary embodiments for generating different wavefronts as illustrated in figures 2, 4 and 5 can be used both separately and in arbitrary combinations with one another. By way of example, it is also possible to
5 combine all three measures with one another, that is to say to arrange a phase plate 12 in an asymmetrical prism 9' in accordance with figure 4 and additionally also to provide the entrance surface 11 with a splitter layer 17 which, moreover, has a varying thickness
10 and/or else is formed in non-homogeneous fashion.